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Substitute for form 1449B/PTO Complete if Known Application Number INFORMATION DISCLOSURE 10/849,348 Filing Date May 19, 2004 STATEMENT BY APPLICANT First Named Inventor Robert H. Burgener, II Group Art Unit (use as many sheets as necessary) Examiner Namo Sheet Of 3398.2.10 Attorney Docket Number

		NON PATENT LITERATURE DOCUMENTS	
Examiner Initials *	Cite No. ³	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T 2
4/50	01	Itani, Kenya, et al., "Low-Dislocation-Density GaAs Wafers Grown by Vertical Gradient Freeze Process, Suitable for Mass Production of Semiconductor Lasers," Hitachi Cable Review No. 20, August 2001, pp. 35-38	
1	02	Look, D.C., et al. "The Future of ZnO Light Emitters," Phys. Stat. Sol. (2004), pp. 1-10	
	03	Pearton, S.J., et al. "Wide Band Gap Ferromagnetic Semiconductors and Oxides," Journal of Applied Physics Vol. 93, No. 1, January 1, 2003, pp. 1-13	
1	04	Web Page '99 SBIR Phase ITopic 14 – Electronic Materials, http://www-ee.eng.buffalo.edu/faculty/paololin/492/semicon.pdf, "Low-Temperature Hydrothermal Growth of Zno for Seminconductor Substrates," 2/26/04, 2 pages	
A	O5	Web Page "Semiconductor Photonics", 3 pages	

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Complete if Known Application Number 10/849.348 Filing Date May 19, 2004 Robert H. Burgener, II First Named Inventor Group Art Unit Examiner Name

3398.2.10

(use as many sheets as necessary)

Sheet

			U.S. PATENT	DOCUMENTS		
Examiner		Document Number	Publication Date	Name of Patentee or Applicant of	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
Initials *	Cite No.'	Number - Kind Code ^{2 (F known)}	MM-DD-YYYY	Cited Document		
WSI	U1	US-3,664,867-B1	05/23/1972	Galli et al.		
WSZ	U2	US-4,399,441-B1	08/16/1983	Vaughn et al.		

Attorney Docket Number

FOREIGN PATENT DOCUMENTS						
Examiner	Cite No.1	Foreign Patent Document	Publication Date		Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
Initials*		Country Code ³ - Number ⁴ - Kind Code ⁴ (* ^{Linourity}	MM-DD-YYYY			
WSL	F1	EP - 1219731-A1	07/03/2002	Yoshida, et al.		
WSV	F2	JP 2002-68890-AI	03/08/2002	Ogata, et al.		

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